

IFW



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Appln. Of: ASPAR et al.

Serial No.: 10/784,601

Filed: February 23, 2004

For: A METHOD FOR PRODUCING A THIN LAYER OF SEMICONDUCTOR MATERIAL

Group: 2823 Confirmation No. 8343

Examiner: Fourson, III, George R. DOCKET: BREV 12370 CON4

MAIL STOP ISSUE FEE  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT UNDER RULE 312 AND COMMENTS ON STATEMENT OF REASONS FOR ALLOWANCE**

Dear Sir:

This Amendment is being filed in response to the Notice of Allowance mailed September 22, 2005.

Please amend the Application as follows:

**Amendments to the Claims** begin on page 2 of this Amendment.

**Comments on Statement of Reasons for Allowance and Remarks** begin on page 4 of this Amendment.

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